

Vishay Siliconix

Complementary 20 V (D-S) MOSFET

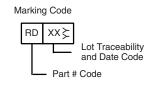
PRODUCT SUMMARY							
	V _{DS} (V)	R_{DS(on)} (Ω)	I _D (A)	Q _g (Typ.)			
	20	1.9 at V _{GS} = 4.5 V	0.30				
N-Channel		3.7 at V _{GS} = 2.7 V	0.22	0.72			
		4.2 at V_{GS} = 2.5 V	0.21				
P-Channel	- 20	0.995 at V _{GS} = - 4.5 V	- 0.44				
		1.600 at V _{GS} = - 2.7 V	- 0.34	0.52			
		1.800 at V _{GS} = - 2.5 V	- 0.32				

SOT-363 SC-70 (6-LEADS) S_1 1 6 D_1 G_1 2 5 G_2 D_2 3 4 S_2 Top View

FEATURES

- Halogen-free According to IEC 61249-2-21
 Definition
- TrenchFET[®] Power MOSFET: 2.5 V Rated
- Compliant to RoHS Directive 2002/95/EC





Ordering Information: Si1551DL-T1-E3 (Lead (Pb)-free) Si1551DL-T1-GE3 (Lead (Pb)-free and Halogen-free)

Parameter		Symbol	N-Channel		P-Channel		
			5 s	Steady State	5 s	Steady State	Unit
Drain-Source Voltage		V _{DS}	20 - 20		- 20	v	
Gate-Source Voltage		V _{GS}	± 12				v
Continuous Drain Current (T _J = 150 °C) ^a	T _A = 25 °C	Ι _D	0.30	0.29	- 0.44	- 0.41	
	T _A = 85 °C		0.22	0.21	- 0.31	- 0.30	
Pulsed Drain Current		I _{DM}		0.6	- 1.0		A
Continuous Source Current (Diode Conduction) ^a		۱ _S	0.25	0.23	- 0.25	- 0.23	
Maximum Power Dissipation ^a	T _A = 25 °C	Р	0.30	0.27	0.30	0.27	
	T _A = 85 °C	PD	0.16	0.14	0.16	0.14	W
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150				°C

THERMAL RESISTANCE RATINGS								
Parameter		Symbol	Typical Maximu		m Unit			
Maximum Junction-to-Ambient ^a	t ≤ 5 s	R _{thJA}	360	415				
	Steady State	' 'thJA	400	460	°C/W			
Maximum Junction-to-Foot (Drain)	Steady State	R _{thJF}	300	350				

Notes:

a. Surface mounted on 1" x 1" FR4 board.

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Parameter	Symbol	Test Conditions		Min.	Тур.	Max.	Unit	
Static								
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = 250 \ \mu A$	N-Ch	0.6		1.5	v	
		$V_{DS} = V_{GS}, I_D = -250 \ \mu A$	P-Ch	- 0.6		- 1.5	v	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 12 V$	N-Ch			± 100	- 1	
			P-Ch			± 100	nA	
Zero Gate Voltage Drain Current	I _{DSS}	$V_{DS} = 20 \text{ V}, V_{GS} = 0 \text{ V}$	N-Ch			1		
		$V_{DS} = -20 V, V_{GS} = 0 V$			- 1			
		V_{DS} = 20 V, V_{GS} = 0 V, T_{J} = 85 °C	N-Ch			5	μA	
		V_{DS} = - 20 V, V_{GS} = 0 V, T_{J} = 85 °C	P-Ch			- 5		
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge 5$ V, $V_{GS} = 4.5$ V	N-Ch	0.6			_	
		$V_{DS} \leq$ - 5 V, V_{GS} = - 4.5 V	P-Ch	- 1.0			A	
Drain-Source On-State Resistance ^a	R _{DS(on)}	$V_{GS} = 4.5 \text{ V}, \text{ I}_{D} = 0.29 \text{ A}$	N-Ch		1.55	1.9	Ω	
		V _{GS} = - 4.5 V, I _D = - 0.41 A	P-Ch		0.850	0.995		
		V _{GS} = 2.7 V, I _D = 0.1 A	N-Ch		2.8	3.7		
		V _{GS} = - 2.7 V, I _D = - 0.25 A	P-Ch		1.23	1.600		
		V _{GS} = 2.5 V, I _D = 0.1 A	N-Ch		3.0	4.2		
		V _{GS} = - 2.5 V, I _D = - 0.25 A	P-Ch		1.4	1.800		
Forward Transconductance ^a	9 _{fs}	$V_{\rm DS} = 10 \text{ V}, \text{ I}_{\rm D} = 0.29 \text{ A}$	N-Ch		0.3			
		$V_{DS} = -10 \text{ V}, \text{ I}_{D} = -0.41 \text{ A}$	P-Ch		0.8		S	
	V _{SD}	I _S = 0.23 A, V _{GS} = 0 V	N-Ch		0.8	1.2		
Diode Forward Voltage ^a		I _S = - 0.23 A, V _{GS} = 0 V	P-Ch		- 0.8	- 1.2	V	
Dynamic ^b								
Tatal Cata Charge	Q _g Q _{gs}		N-Ch		0.72	1.5		
Total Gate Charge		N-Channel $V = 10 V V = 45 V L = 0.29 A$	P-Ch		0.52	1.8		
Gate-Source Charge		$V_{DS} = 10 \text{ V}, V_{GS} = 4.5 \text{ V}, I_{D} = 0.29 \text{ A}$	N-Ch		0.22		nC	
		P-Channel	P-Ch		0.11			
Gate-Drain Charge	Q _{gd}	V_{DS} = - 10 V, V_{GS} = - 4.5 V, I_{D} = - 0.41 A	N-Ch		0.13			
0			P-Ch		0.14		┼──	
Turn-On Delay Time	t _{d(on)} t _r	N-Channel	N-Ch		23	40		
		$V_{DD} = 10 \text{ V}, \text{ R}_{L} = 20 \Omega$	P-Ch N-Ch		7.5 30	15 60		
Rise Time		$\text{I}_\text{D} \cong \text{0.5}$ A, V_GEN = 4.5 V, R_g = 6 Ω	P-Ch		20	40		
	t _{d(off)}		N-Ch		10	20	_	
Turn-Off Delay Time		P-Channel V _{DD} = - 10 V, R _L = 20 Ω	P-Ch		8.5	17	ns	
	t _f	$V_{DD} = -100$, $H_L = 2032$ $I_D \cong -0.5$ A, $V_{GEN} = -4.5$ V, $R_q = 6 \Omega$	N-Ch		15	30		
Fall Time			P-Ch		12	24		
	+	I _F = 0.23 A, dl/dt = 100 A/μs	N-Ch		20	40		
Source-Drain Reverse Recovery Time	t _{rr}	I _F = - 0.23 A, dl/dt = 100 A/μs	P-Ch 25			40	1	

Notes:

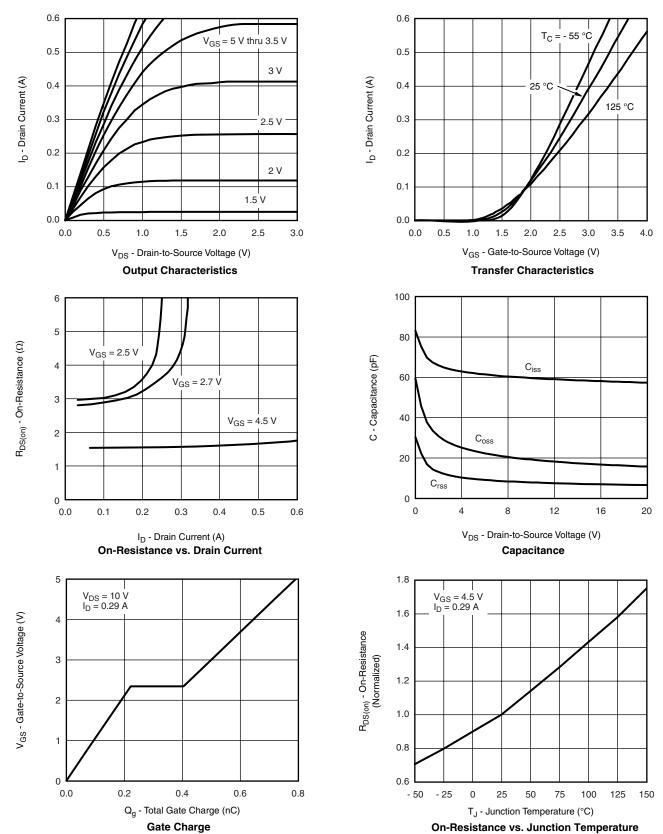
a. Pulse test; pulse width \leq 300 $\mu s,$ duty cycle \leq 2 %.

b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



N-CHANNEL TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



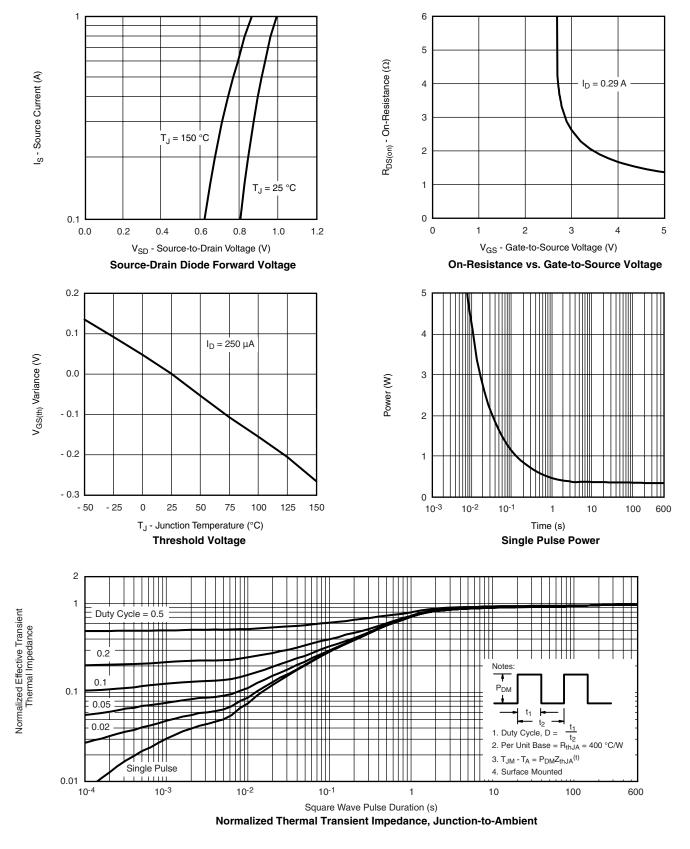
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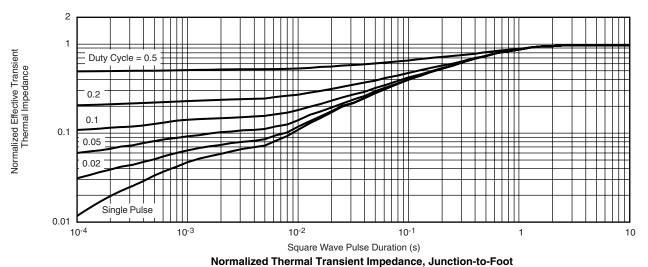
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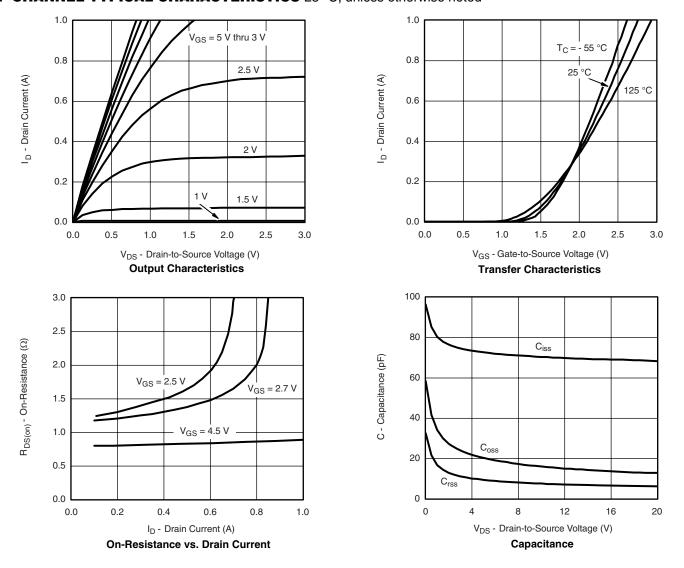


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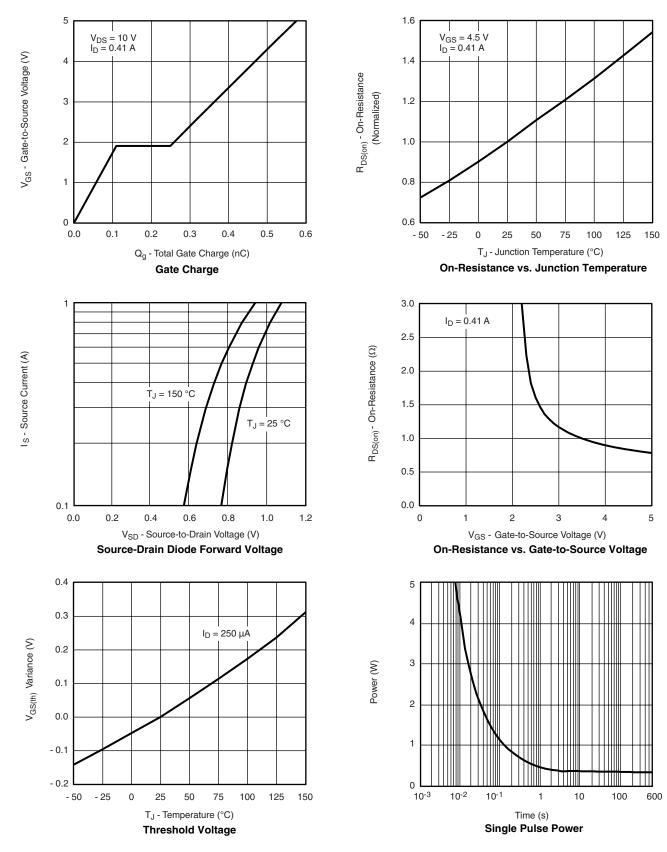
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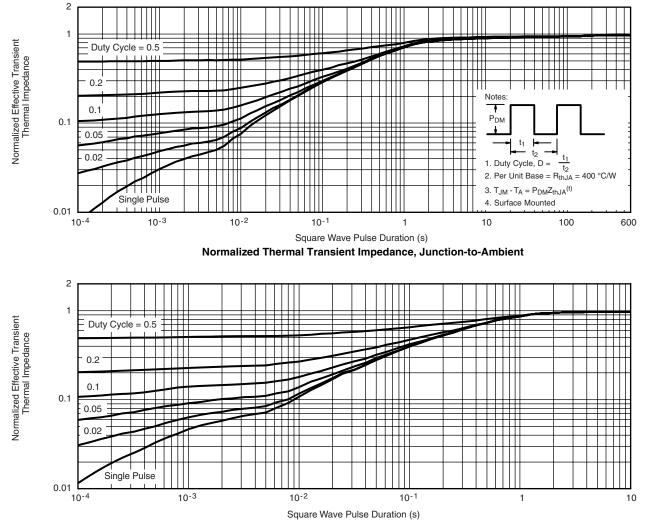
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P-CHANNEL TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



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P-CHANNEL TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

Normalized Thermal Transient Impedance, Junction-to-Foot

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?71078.



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